Special Issue

RF and Power Electronic Devices and Applications

Message from the Guest Editors

The advent of 5G and beyond 5G (B5G) wireless networks is revolutionizing connectivity, enabling faster speeds and significantly enhancing the quality of life through applications like smart cities, autonomous vehicles, and the Internet of Things (IoT). Concurrently, electric vehicles (EVs) are capturing an increasing share of the market, promising a more efficient and sustainable future by reducing carbon emissions and reliance on fossil fuels. These advancements create substantial demands for high-performance semiconductor devices, particularly in the fields of RF and power electronics, where wide-bandgap (WBG) devices are playing a crucial role in achieving superior efficiency and reliability.

This Special Issue aims to gather cutting-edge developments in novel RF and power electronics devices and their applications. We welcome contributions covering, but not limited to, the following topics:

Wide-bandgap devices (GaN, Ga2O3, AIN, etc.) and applications;

High-frequency RF/mmWave device and applications; Advanced device processing;

Device reliability:

Device characterization;

Gate driver design for semiconductors;

WBG-based power converters.

Guest Editors

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About the Journal

Message from the Editor-in-Chief

You are invited to contribute research articles or comprehensive reviews for consideration and publication in *Micromachines* (ISSN 2072-666X). *Micromachines* is published in the open access format. Research articles, reviews and other contents are released on the internet immediately after acceptance. The scientific community and the general public have unlimited free access to the content as soon as it is published. As an open access journal, *Micromachines* is supported by the authors or their institutes by payment of article processing charges (APC) for accepted papers. We are pleased to welcome you as our authors.

Editor-in-Chief

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